

< C band internally matched power GaAs FET >

MGFC41V3642

3.6 - 4.2 GHz BAND / 10W

DESCRIPTION

The MGFC41V3642 is an internally impedance-matched GaAs power FET especially designed for use in 3.6 – 4.2 GHz band amplifiers. The hermetically sealed metal-ceramic package guarantees high reliability.

FEATURES

Internally matched to 50(ohm) system

• High output power

P1dB=14W (TYP.) @f=3.6 - 4.2GHz

• High power gain

GLP=12.5dB (TYP.) @f=3.6 - 4.2GHz

• High power added efficiency

P.A.E.=40% (TYP.) @f=3.6 - 4.2GHz

• Low distortion [item -51]

IM3=-45dBc (Typ.) @Po=30.0dBm S.C.L

APPLICATION

• item 01: 3.6 - 4.2GHz band microwave high power amplifier

• item 51: 3.6 – 4.2GHz band digital radio communication

QUALITY

• IG

RECOMMENDED BIAS CONDITIONS

• VDS=10V • ID=3.4A • RG=50ohm Refer to Bias Procedure

Absolute maximum ratings

Symbol	Parameter	Ratings	Unit					
VGDO	Gate to drain breakdown voltage	-15	V					
VGSO	Gate to source breakdown voltage	-15	V					
ID	Drain current	12	Α					
IGR	Reverse gate current	-30	mA					
IGF	Forward gate current	63	mA					
PT *1	Total power dissipation	57.7	W					
Tch	Cannel temperature	175	°C					
Tstg	Storage temperature	-65 to +175	°C					
*4 F 0500								

^{1:} Tc=25°C

Symbol	Parameter	Test conditions		Limits		
			Min.	Тур.	Max.	
IDSS	Saturated drain current	VDS=3V, VGS=0V	-	-	12	Α
gm	Trans conductance	VDS=3V, ID=3.0A	-	3	-	S
VGS(off)	Gate to source cut-off voltage	VDS=3V,ID=30mA	-	-	-5	V
P1dB	Output power at 1dB gain compression		40	41.5	-	dBm
GLP *2	Linear Power Gain	VDS=10V,ID(RF off)=3.4A	11	12.5	-	dB
P.A.E.	Power added efficiency	f=3.6 – 4.2GHz	-	40	-	%
ID	Drain current	Pin=22dBm *2	-	3.3	-	А
IM3 *3	3rd order IM distortion		-42	-45-	-	dBc
Rth(ch-c) *4	Thermal resistance	delta Vf method	-	=	2.6	°C/W

^{*3 :}item -51, 2 tone test,Po=30.0dBm Single Carrier Level ,f=4.2GHz,delta f=10MHz

OUTLINE Unit: mm 24±0.3 0.6±0.15 R1. 2±0. 2 ₽. (3) 20. 4 ± 0.2 2.4±0. 13. 4 ± 0.3 0.1±0. (1)gate 2)source(frange)

3drain

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^{*4 :}Channel-case

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